

Capacitor Assemblies - ST & SM

These ranges of both High Capacitance and High Voltage MLC assemblies are available in COG and X7R dielectrics.

Low ESR and Low ESL are inherent in the design giving the assemblies a high capability up to 1MHz and offer far superior performance than either Aluminum or Tantalum electrolytic capacitors.

They are designed for use in high power or high frequency applications such as switched mode power supplies, DC-DC converters, high capacitance discharge circuits, high temperature filtering/decoupling.

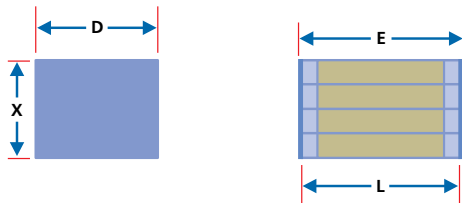
They can be made with up to five same size chips with various lead configurations to safeguard against thermal and mechanical stresses.

The commercial 'ST' series provide the highest capacitance available and are 100% tested for Dielectric Withstanding Voltage, Insulation Resistance, Capacitance, and Dissipation Factor.

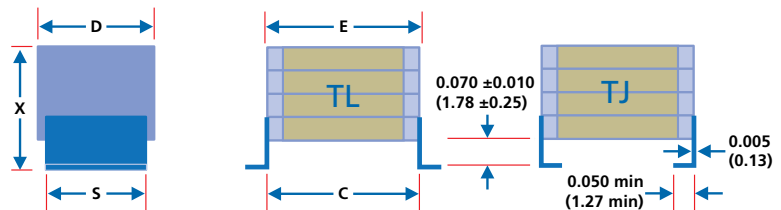
In contrast, the High Reliability 'SM' series is designed and tested for military and industrial applications and tested as per of MIL-PRF-49470 (DSCC 87106), Group A.

Dimensions - inches/mm

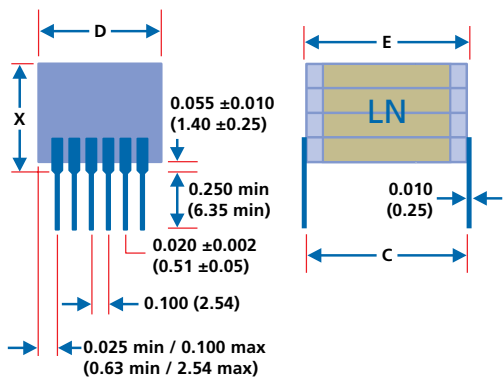
NN or NP (no leads)



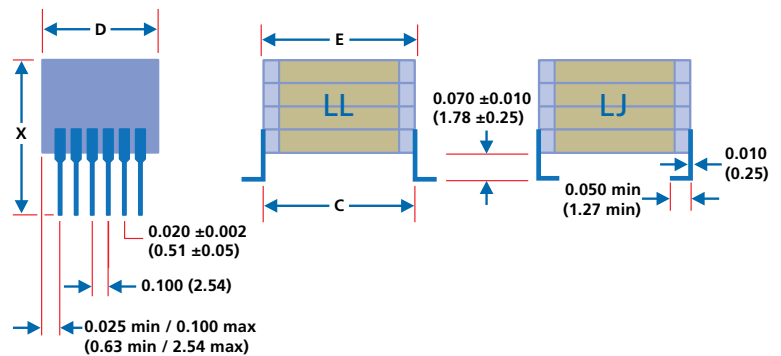
TJ & TL (tab leads)



LN (straight wire leads)



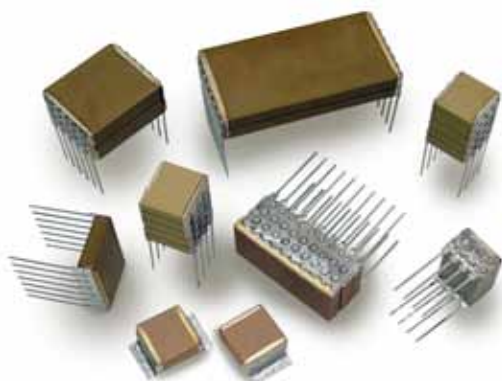
LJ & LL (bent wire leads)



Size	1812	1825	2225	3640	4540	5550	7565
C inches ± 0.025 /mm ± 0.64 :	0.210/5.33	0.210/5.33	0.250/6.35	0.400/10.20	0.480/12.20	0.580/14.70	0.780/19.80
D inches ± 0.025 /mm ± 0.64 :	0.125/3.18	0.250/6.35	0.250/6.35	0.400/10.20	0.400/10.20	0.500/12.70	0.650*/16.50
E max inches/mm:	0.260/6.60	0.260/6.60	0.300/7.62	0.430/10.90	0.530/13.50	0.630/16.00	0.830/21.10
L nom inches/mm:	0.180/4.57	0.180/4.57	0.220/5.59	0.360/9.14	0.450/11.40	0.550/14.00	0.750/19.10
Leads per side	N/A	3	3	4	4	5	6

* ± 0.035 /1.89

Capacitor Assemblies - ST & SM



Our complete testing facility is available for any additional military testing requirements.

Options available include thru-hole and surface mount lead styles, to make them suitable for mounting on ceramic substrates or epoxy PCBs.

Consult the Sales Office if your specific requirements exceed our catalog maximums (size, cap. value, and voltage).

Maximum stack height, X dimension - inches/mm

No. of chips	Chip size	Style NN, NP	Style TJ & TL	Style LN, LJ & LL
1	1812	0.100/2.54	0.180/4.57	N/A
	1825	0.100/2.54	0.180/4.57	0.180/4.57
	2225	0.120/3.05	0.200/5.08	0.200/5.08
	>2225	N/A	0.200/5.08	0.200/5.08
2	1812	0.200/5.08	0.280/7.11	N/A
	1825	0.200/5.08	0.280/7.11	0.280/7.11
	2225	0.240/6.10	0.320/8.13	0.320/8.13
	>2225	N/A	0.320/8.13	0.320/8.13
3	812	0.300/7.62	0.380/9.65	N/A
	1825	0.300/7.62	0.380/9.65	0.380/9.65
	2225	0.360/9.14	0.440/11.2	0.440/11.20
	>2225	N/A	0.440/11.2	0.440/11.20
4	1812	0.400/10.20	0.480/12.2	N/A
	1825	0.400/10.20	0.480/12.2	0.480/12.20
	2225	0.480/12.20	0.560/14.2	0.560/14.20
	>2225	N/A	0.560/14.2	0.560/14.20
5	1812	0.520/13.20	0.600/15.2	N/A
	1825	0.520/13.20	0.600/15.2	0.600/15.2
	2225	0.635/16.10	0.715/18.2	0.715/18.2
	>2225	N/A	0.715/18.2	0.715/18.2

How to Order - ST & SM Capacitor Assemblies

ST	3640	B	474	M	101	LJ	X	W	5
STYLE ST = Commercial SM = High Reliability	SIZE See Chart	DIELECTRIC N = COG B = X7R	CAPACITANCE Value in Picofarads. Two significant figures, followed by number of zeros: 825 = 8,200,000pF (8.2μF)	TOLERANCE F = ±1%* G = ±2%* H = ±3%* J = ±5% K = ±10% M = ±20% Z = +80 -20% P = +100 -0% *COG only	VOLTAGE-VDCW Two significant figures, followed by number of zeros: 101 = 100V	LEAD STYLE LN = Straight* LL = L Lead* LJ = J Lead* TL = L Tab TJ = J tab NN = Nickel* NP = Pd/Ag *Not 1812	THICKNESS OPTION Specify standoff dimension if less than max.	PACKING W = Waffle T = Tape & Reel* *Consult the sales office	No. Chips 1 to 5

[illegible]

Capacitor Assemblies - ST & SM - C0G



C0G Capacitance & Voltage Selection

Note: Capacitance values are shown as 3 digit code:
2 significant figures followed by the no. of zeros e.g. 183 = 18,000pF.

	Size	4540								5550								6560								7565								Size
	Rated Voltage	50V		100V		200V		500V		50V		100V		200V		500V		50V		100V		200V		500V		50V		100V		200V		500V		Rated Voltage
	Type	ST	SM	ST	SM	ST	SM	ST	SM	ST	SM	ST	SM	ST	SM	ST	SM	ST	SM	ST	SM	ST	SM	ST	SM	ST	SM	ST	SM	ST	SM	Type		
	Capacitance Values					Number of chips required to achieve the capacitance value																												100
																																	120	
																																		150
																																		180
																																		220
																																		270
																																		330
	390	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	390	
	470	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	470	
	560	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	560	
	680	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	680	
	820	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	820	
	101	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	101	
	121	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	121	
	151	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	151	
	181	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	181	
	221	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	221	
	271	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	271	
	331	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	331	
	391	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	391	
	471	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	471	
	561	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	561	
	681	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	681	
	821	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	821	
	102	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	102	
	122	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	122	
	152	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	152	
	182	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	182	
	222	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	222	
	272	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	272	
	332	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	332	
	392	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	392	
	472	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	472	
	562	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	562	
	682	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	682	
	822	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	822	
	103	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	103	
	123	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	123	
	153	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1																	

Note: Capacitance values are shown as 3 digit code: 2 significant figures followed by the no. of zeros e.g. 183 = 18,000pF.

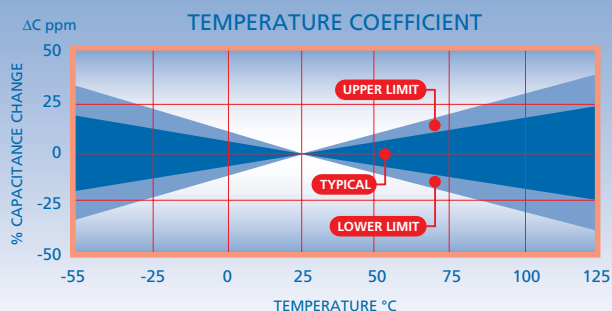
Capacitance Values



Dielectric Characteristics

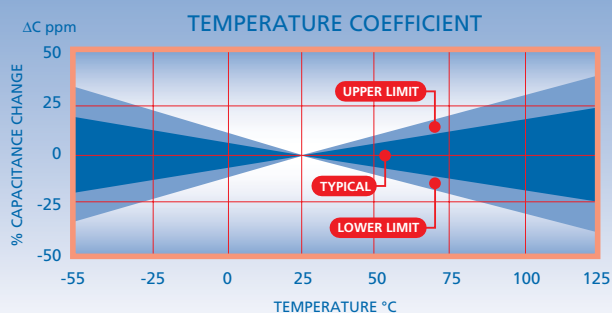
C0G/NP0 (N) Ultra Stable and RoHS 2013 (RN) type

Operating temperature range:	-55°C to 125°C
Temperature coefficient:	0 ±30 ppm/°C
Dissipation factor:	0.1% max @ 25°C
Insulation resistance	@25°C: >100GΩ or >1000ΩF whichever is less @125°C: >10GΩ or >100ΩF whichever is less
Dielectric withstanding voltage	≤200V: 250% 201-500V: 150% or 500V whichever is greater >500V: 120% or 750V whichever is greater
Ageing rate:	0% per decade
Test parameters:	1KHz, 1.0 ±0.2 VRMS, 25°C 1MHz for Capacitance ≤100pF



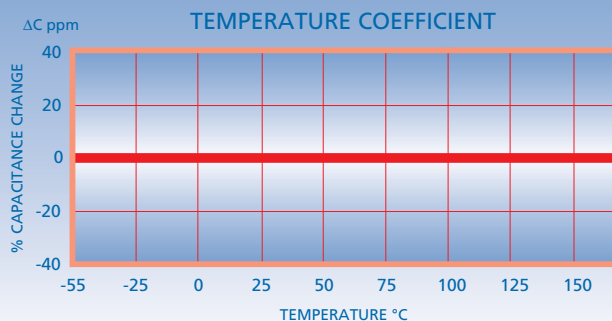
C0G/NP0 (M) Ultra Stable Non Magnetic

Operating temperature range:	-55°C to 125°C
Temperature coefficient:	0 ±30 ppm/°C
Dissipation factor:	0.1% max @ 25°C
Insulation resistance	@25°C: >1000ΩF or >10000ΩF whichever is less @125°C: >100ΩF or >1000ΩF whichever is less
Dielectric withstanding voltage	≤200V: 250% 201-500V: 150% or 500V whichever is greater >500V: 120% or 750V whichever is greater
Ageing rate:	0% per decade
Test parameters:	1KHz, 1.0 ±0.2 VRMS, 25°C 1MHz for Capacitance ≤100pF



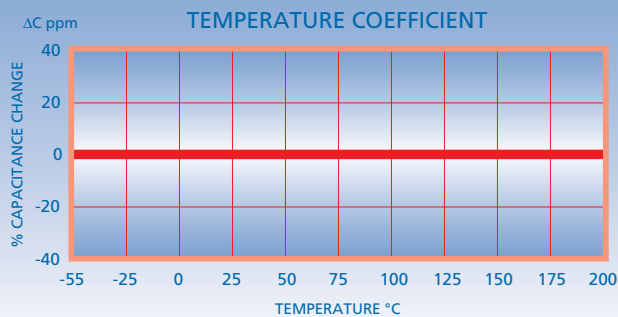
C0G/NP0 (F) Ultra Stable High Temperature (up to 160°C)

Operating temperature range:	-55°C to 160°C
Temperature coefficient:	0 ±30 ppm/°C
Dissipation factor:	0.1% max @ 25°C
Insulation resistance	@25°C: >100GΩ or >1000ΩF whichever is less @160°C: >1GΩ or >10ΩF whichever is less
Dielectric withstanding voltage	≤200V: 250% 201-500V: 150% or 500V whichever is greater >500V: 120% or 750V whichever is greater
Ageing rate:	0% per decade
Test parameters:	1KHz, 1.0 ±0.2 VRMS, 25°C 1MHz for Capacitance ≤100pF



C0G/NP0 (D) Ultra Stable High Temperature (up to 200°C)

Operating temperature range:	-55°C to 200°C
Temp. coefficient ≤200°C:	0 ±30 ppm/°C
Dissipation factor @ 25°C:	0.1% Max.
Insulation resistance	@25°C: >100GΩ or >1000ΩF whichever is less @200°C: >1GΩ or >10ΩF whichever is less
Dielectric withstanding voltage	≤200V: 250% 201-500V: 150% or 500V whichever is greater >500V: 120% or 750V whichever is greater
Ageing rate:	0% per decade
Test parameters:	1KHz, 1.0 ±0.2 VRMS, 25°C 1MHz for capacitance ≤100pF

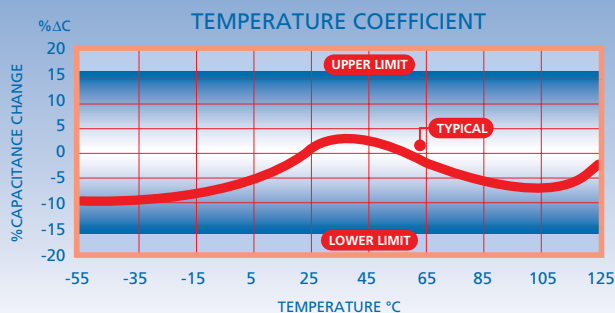




Dielectric Characteristics

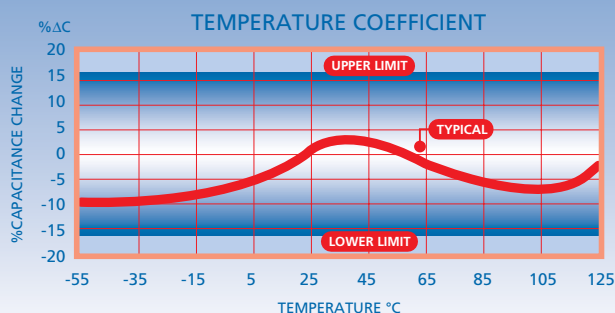
X7R (B) Stable and RoHS 2013 (RB) type

Operating temperature range:	-55°C to 125°C
Temperature coefficient :	±15% ΔC Max.
Dissipation factor	>25V rating: 2.5% max ≤25V rating: 3.5% max
Insulation resistance:	@25°C: >100GΩ or >1000ΩF whichever is less @125°C: >10GΩ or >100ΩF whichever is less
Dielectric withstanding voltage	≤200V: 250% 201-500V: 150% or 500V whichever is greater >500V: 120% or 750V whichever is greater
Ageing rate:	<2.0% per decade
Test parameters:	1KHz, 1.0 ±0.2 VRMS, 25°C



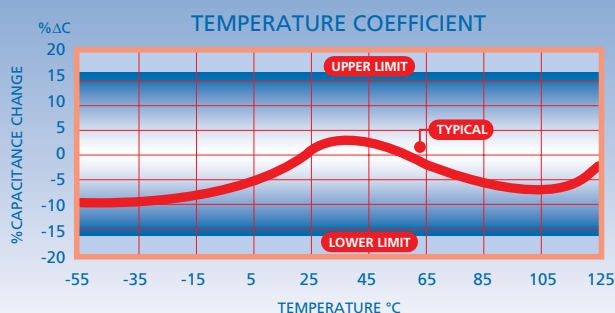
X7R (C) Stable Non Magnetic

Operating temperature range:	-55°C to 125°C
Temperature coefficient:	±15% ΔC Max.
Dissipation factor	>25V rating: 2.5% max ≤25V rating: 3.5% max
Insulation resistance:	@25°C: >100GΩ or >1000ΩF whichever is less @125°C: >10GΩ or >100ΩF whichever is less
Dielectric withstanding voltage	≤200V: 250% 201-500V: 150% or 500V whichever is greater >500V: 120% or 750V whichever is greater
Ageing rate:	<2.0% per decade
Test parameters:	1KHz, 1.0 ±0.2 VRMS, 25°C



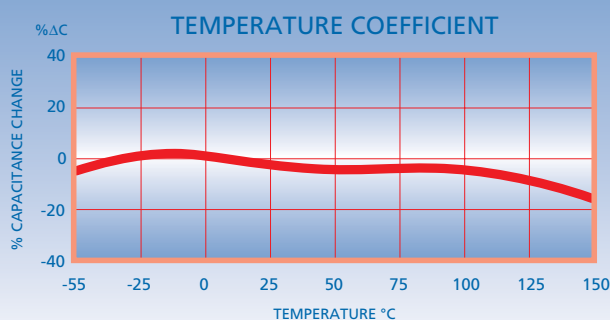
BX (X) Stable

Operating temperature range:	-55°C to 125°C
Temperature coefficient:	±15% ΔC Max.
Temp-voltage coefficient:	+15% -25% ΔC Max.
Dissipation factor	>25V rating: 2.5% max ≤25V rating: 3.5% max
Insulation resistance:	@25°C: >100GΩ or >1000ΩF whichever is less @125°C: >10GΩ or >100ΩF whichever is less
Dielectric withstanding voltage	≤200V: 250% 201-500V: 150% or 500V whichever is greater >500V: 120% or 750V whichever is greater
Ageing rate:	<2.0% per decade
Test parameters:	1KHz, 1.0 ±0.2 VRMS, 25°C



X8R (S) Stable

Operating temperature range:	-55°C to 150°C
Temp. coefficient ≤150°C:	±15% ΔC Max.
Dissipation factor	>25V rating: 2.5% max ≤25V rating: 3.5% max
Insulation resistance	@25°C: >100GΩ or >1000ΩF whichever is less @150°C: >10GΩ or >100ΩF whichever is less
Dielectric withstanding voltage	≤200V: 250% 201-500V: 150% or 500V whichever is greater >500V: 120% or 750V whichever is greater
Ageing rate:	<2.0% per decade
Test parameters:	1KHz, 1.0 ±0.2 VRMS, 25°C



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